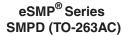
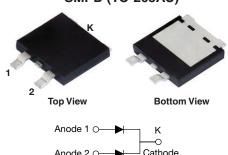


Ultrafast Rectifier, 2 x 15 A FRED Pt®





LINKS TO ADDITIONAL RESOURCES

Anode 2 O-



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 15 A			
V_{R}	600 V			
V _F at I _F	0.9 V			
t _{rr}	55 ns			
T _J max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

FEATURES

• Ultrafast recovery time, reduced Q_{rr}, and soft recovery



• 175 °C maximum operating junction temperature

• For PFC CRM, snubber operation

COMPLIANT HALOGEN FREE

· Low forward voltage drop

Low leakage current

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V _{RRM}		600	V
Average rectified forward current -	per device	I _{F(AV)}	T - 142 °C	30	
	per diode		T _{solder pad} = 143 °C	15	۸
Non-repetitive peak surge current per devi	per device	I _{FSM}	T _J = 25 °C, 6 ms square pulse	300	А
Non-repetitive peak surge current	per diode			160	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-	
Forward voltage, per diode	V _F	I _F = 15 A	-	1.03	1.25	V
r orward vortage, per diode	٧F	I _F = 15 A, T _J = 150 °C	-	0.9	1.1	
Reverse leakage current, per diode		$V_R = V_R$ rated	-	-	15	
Reverse leakage current, per diode		$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	70	300	μΑ
Junction capacitance, per diode	C _T	V _R = 600 V	-	13	-	pF



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A, dI_F/dt = 50 A$	/μs, V _R = 30 V	-	55	-	
B	+	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	-	65	1
Reverse recovery time	t _{rr}	T _J = 25 °C		-	96	-	ns
		T _J = 125 °C		=.	150	-	
Dook roopyony gurrent	1	T _J = 25 °C	$I_F = 15 \text{ A},$	-	18	-	^
Peak recovery current I _{RRM}	T _J = 125 °C	$dI_F/dt = 500 A/\mu s$, $V_R = 400 V$	-	26	- A	A	
Payaraa raaayan, aharaa	Nyeroe recovery charge	T _J = 25 °C		-	1.0	-	
Reverse recovery charge	Q_{rr}	T _J = 125 °C		-	2.0	-	μC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C
Thermal resistance, per diode junction to mount	R _{thJM}		-	1.2	1.7	°C/W
Approximate weight				0.55		g
Approximate weight				0.02		oz.
Marking device		Case style SMPD (TO-263AC)		30CI	DU06	•

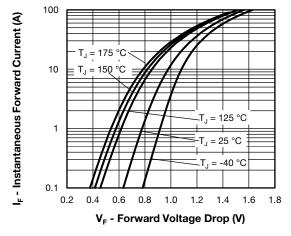


Fig. 1 - Typical Forward Voltage Drop Characteristics

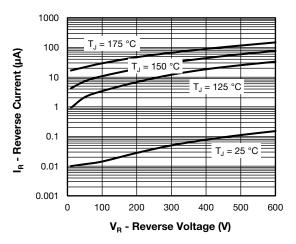


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

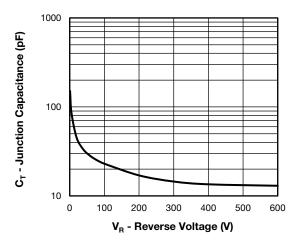


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

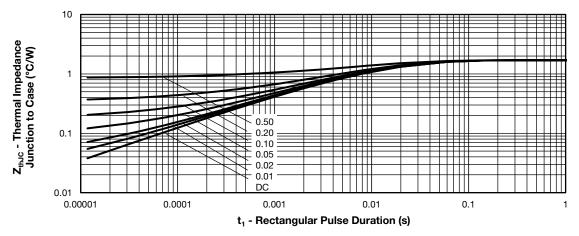


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

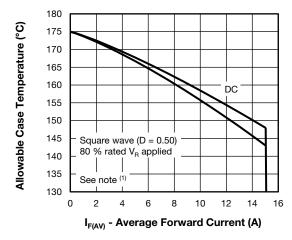


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

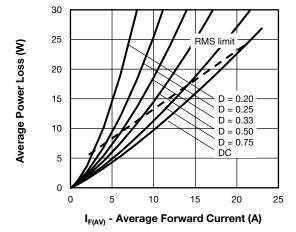


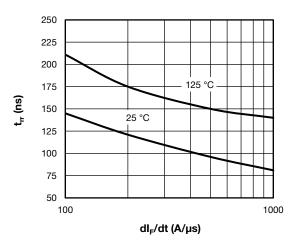
Fig. 6 - Forward Power Loss Characteristics

Note

 $[\]begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times R_{\text{thJC}}; \\ \text{Pd} = & \text{forward power loss} = I_{\text{F(AV)}} \times V_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/D) \text{ (see fig. 5)}; \\ \text{Pd}_{\text{REV}} = & \text{inverse power loss} = V_{\text{R1}} \times I_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } V_{\text{R1}} = \text{rated } V_{\text{R}} \\ \end{array}$

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Vishay Semiconductors



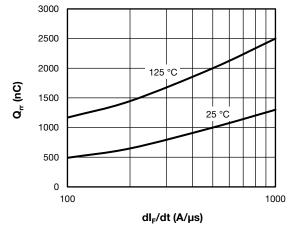
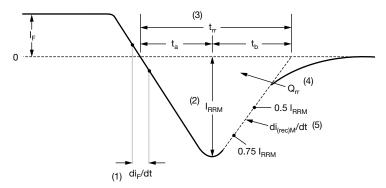


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 8 - Typical Stored Charge vs. dl_E/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) \boldsymbol{Q}_{rr} area under curve defined by \boldsymbol{t}_{rr} and \boldsymbol{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

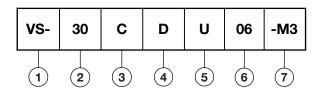
(5) $di_{(rec)M}/dt$ - peak rate of change of current during $t_{\rm b}$ portion of $t_{\rm rr}$

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 A)

3 - Circuit configuration:

C = common cathode

4 - D = SMPD package

5 - Process type,

U = ultrafast recovery

6 - Voltage code (06 = 600 V)

7 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

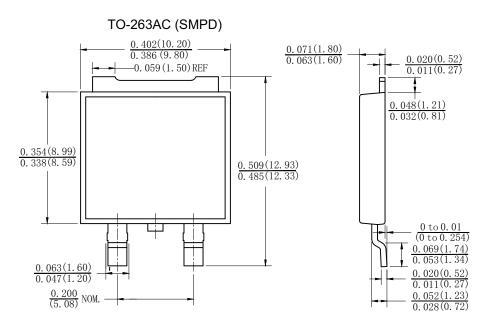
ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-30CDU06-M3/I	2000	2000	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95604			
Part marking information	www.vishay.com/doc?95566			
Packaging information	www.vishay.com/doc?88869			
SPICE model	www.vishay.com/doc?96576			

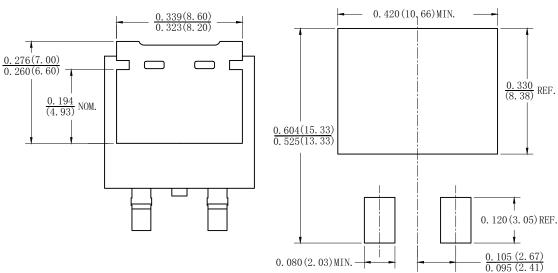


TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)



Mounting Pad Layout





Legal Disclaimer Notice

Vishay

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